BU2530AL

GENERAL DESCRIPTION

New generation, high-voltage, high-speed switching npn transistor in a plastic envelope intended for use in horizontal deflection circuits of large screen colour television receivers up to 32 kHz.

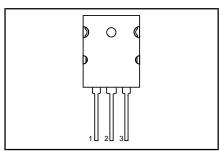
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V_{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)		-	800	. V
I _C	Collector current (DC)		-	16	A
1 1	Collector current peak value		-	40	A
P _{tot}	Total power dissipation	$T_{mb} \leq 25 ^{\circ}C$	-	125	W
P _{tot} V _{CEsat}	Collector-emitter saturation voltage	$T_{mb} \le 25 \degree C$ $I_C = 9.0 \text{ A}; I_B = \text{tbf}$	-	5.0	V
I _{Csat}	Collector saturation current		9	-	Α
t _s	Storage time	$I_{CM} = 9.0 \text{ A}; I_{B(end)} = \text{tbf}$	-	4.5	μs

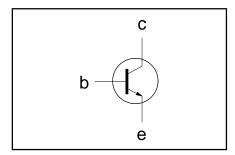
PINNING - SOT430

PIN	DESCRIPTION
1	base
2	collector
3	emitter
heat sink	collector

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{RF} = 0 \text{ V}$	-	1500	V
V _{CEO}	Collector-emitter voltage (open base)		-	800	V
I _C	Collector current (DC)		-	16	Α
I I _{CM}	Collector current peak value		-	40	Α
I _B	Base current (DC)		-	16	Α
I _{BM}	Base current peak value		-	30	Α
-I _{B(AV)}	Reverse base current	average over any 20 ms period	-	200	mΑ
-I _{BM}	Reverse base current peak value 1		-	30	Α
P _{tot}	Total power dissipation	$T_{mb} \leq 25 ^{\circ}C$	-	125	W
T _{stg}	Storage temperature		-55	150	°C
Tj	Junction temperature		-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-mb}	Junction to mounting base	-	-	1.0	K/W
R _{th j-a}	Junction to ambient	in free air	45	-	K/W

¹ Turn-off current.

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STATIC CHARACTERISTICS

 $T_{mb} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	Collector cut-off current ²	$egin{aligned} V_{BE} &= 0 \ V; \ V_{CE} &= V_{CESMmax} \ V_{BE} &= 0 \ V; \ V_{CE} &= V_{CESMmax}; \end{aligned}$	-	-	1.0	mA
I _{CES}		$V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax};$	-	-	2.0	mA
I _{EBO}	Emitter cut-off current	T _i = 125 °C V _{EB} = 7.5 V; I _C = 0 A	-	_	1.0	mA
BV _{EBO}	Base-emitter breakdown voltage	$I_{R} = 1 \text{ mA}$	7.5	14	-	V
V _{CEOsust}	Collector-emitter sustaining voltage	$I_{B}^{"} = 0 \text{ A}; I_{C} = 100 \text{ mA};$ L = 25 mH	800	-	-	V
V_{CEsat}	Collector-emitter saturation voltage	$I_{c} = 9.0 \text{ A}; I_{B} = \text{tbf}$	-	-	5.0	V
V _{BEsat}	Base-emitter saturation voltage 3	$I_{C} = 9.0 \text{ A}; I_{B} = \text{tbf}$	tbf	tbf	tbf	V
h _{FE}	DC current gain	$I_{\rm C} = 1 \text{ A}; V_{\rm CE} = 5 \text{ V}$	10		30	
h _{FE}		$I_{\rm C} = 9 \text{ A}; V_{\rm CE} = 5 \text{ V}$	tbf	tbf	tbf	

DYNAMIC CHARACTERISTICS

 $T_{mb} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
t _s	Switching times (32 kHz line deflection test circuit). Turn-off storage time Turn-off fall time	$\begin{split} I_{\text{CM}} &= 9.0 \text{ A; } L_{\text{C}} = 250 \mu\text{H; } C_{\text{fb}} = 13 \text{ nF;} \\ I_{\text{B(end)}} &= tbf \end{split}$	1 1	4.5 0.35	μs μs

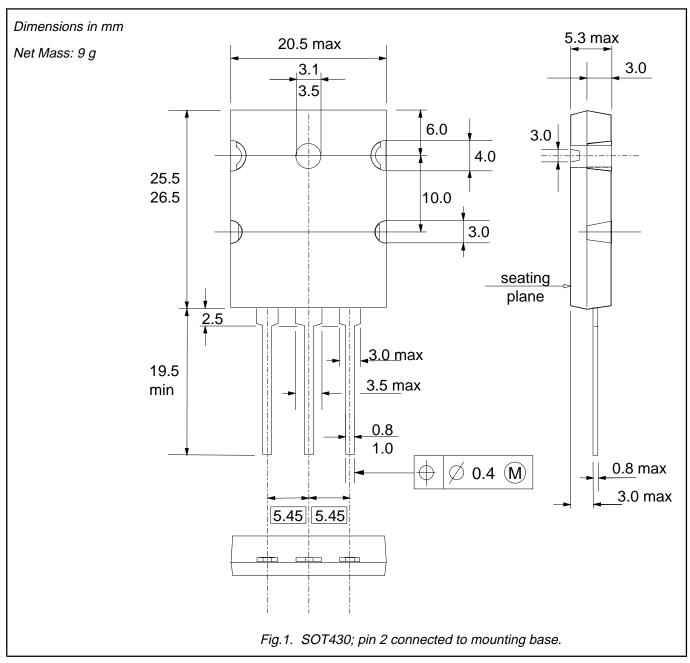
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² Measured with half sine-wave voltage (curve tracer).

³ $\mbox{V}_{\mbox{\scriptsize BEsat}}$ limits are targetted at $\pm\,5\%$ of the 50% value of the distribution of measured values.

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MECHANICAL DATA



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DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limitin or conferen				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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